

tentative

Туре	Ag [*] Aİ [*]	V _{DRM} / V _{RRM}	V _{DSM} /V _{RSM} [∨]	I_{Т(AV)} [A]	Chip Size [mm] x [mm]	Package Options	• 🙀 •
CWP 341-	18 🗹 🗆	1800	1900	283	25.30 18.5	sawn on foil vmnsawn wafer vm in waffle pack vm	
	*Frontside options					*Please contact IXYS chip sales	

Passivation

Mechanical Parameters

Area active			3.40	cm ²
Area total			4.68	cm ²
Wafer size Ø			150	mm
Thickness			380	μm
Material			Si	
Max. possible chips per wafer			26	X
Passivation front side	Glassivation			
Metallization top side	solderable:Ti / Ni / Ag *			
top side	bond	dable:	ΑI	
Recom. wire bonds (AI)	Cathode Gate			
Number / Ø [μm]	/	/		
Metallization backside	solderable (only):Ti / Ni / Ag *			
Reject Ink Dot Size		Ø	1	mm
Recom. Storage Environment				
sawn on foil	in org. container, in dry	nitrogen	< 6	month
unsawn wafer	in org. container, in dry	nitrogen	< 2	year
in waffle pack	in org. container, in dry	nitrogen	< 2	year
	T_{stg}	-40	40	°C

Features

- planar design (non-mesa)
- ultra rugged for easy assembly (flat backside)
- excellent long term stability
- very low leakage current
- very low forward voltage drop

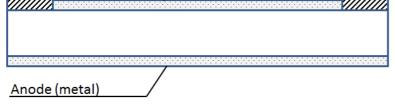
Applications

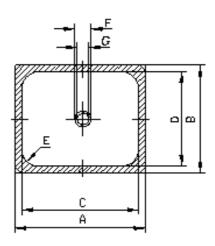
- DC motor control
- AC power control
- Softstrart AC motor controller
- Light, heat and temperature control
- Solid state relays
- Controlled rectifier circuits

*Sinterable top/bottom side on request

Dimensions

В С D Е F G [mm] [mm] [mm] [mm] [mm] [mm] [mm] 25.30 | 18.50 | 22.70 | 15.90 3.90 3.50 2.50 Cathode (metal)





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			Ratings		
Symbol	Conditions	mi	n. typ.	max.	
I _R	$V_D = Vr = Vrr$	$T_{VJ} = 25^{\circ}C$		0.3	m
		$T_{VJ} = 150$ °C		40	m
V ₇	I _T =600 A	$T_{VJ} = 25 ^{\circ}\text{C}$	1	1.20	
		T _{v,j} = 150 °C		1.17	
$V_{\tau o}$	For power-loss	s calculations only		0.86	
r 7	T _{vJ} = 150 °C			0.50	m
V_{g7}	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$	\times	2	
		$T_{VJ} = -40$ °C	4	3	
l _{et}	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$	>	145	m
		$T_{VJ} = -40$ °C		220	m
V_{GD}	$T_{VJ} = 150 ^{\circ}\text{C}$	$V = \frac{2}{3} V_{DRM}$		0.25	
l _{gD}				10	m
I <u>L</u>	$t_p = 30 \ \mu s$	$T_{VJ} = 25^{\circ}C$ $I_{G} = 0.45 \text{ A} \text{ di}_{G}/\text{dt} = 0.45 \text{ A}/\mu\text{s}$		200	m
I _H	R _{GK} = ∞	$T_{VJ} = 25^{\circ}C$ $V_{D} = 6 \text{ V}$		150	m
t _{gd}	$V_D = \frac{1}{2} V_{DRM}$	$T_{VJ} = 25$ °C		2	ŀ
	$I_{\rm G} = 0.5 {\rm A}$	$di_{G}/dt = 0.5 A/\mu$			
t _q	V _R = 100 V	$I_{T} = 300 \text{ A}$ $-di/dt = 10 \text{ A/}\mu\text{s}$		200	ŀ
•	$t_p = 200 \mu s$	$dv/dt = 50 V/\mu s V_D = \frac{2}{3} V drm T_{V,I} = 150 °C$			
(di/dt) _c ,	repetitive	$I_{T} = 600 \text{ A}$		100	A/μ
	non repetitive	I _T = 283 A		500	A/µ
	$V = \frac{2}{3} V_{DRM}$	$T_{VJ} = 150 ^{\circ}\text{C}$ $di_{G}/dt = 0.45 A/\mu s$			
	$I_{G} = 0.45 \text{ A}$	$t_p = 200 \ \mu s$ $f = 50 \ Hz$			
(dv/dt) _c ,	$T_{VJ} = 150 ^{\circ}\text{C}$	$V_{DR} = \frac{2}{3} V_{DRM}$		1000	V/µ
	R _{GK} = ∞	method 1 (linear voltage rise)			
P _{GM}	$T_{VJ} = 150 ^{\circ}\text{C}$	$t_p = 30 \mu\text{s}$		120	٧
		$t_p = 5E \mu s$		60	٧
P _{GAV}				20	V
V _{rgm}				10	
T _{VJ}		-4	0	150	٥
I _{T(AV)}	$T_{c} = 100 ^{\circ}C$	180° rect.		283	
	$T_{VJ} = {}^{\circ}C$	180° sine		tbd	
I _{tsm} *	$T_{VJ} = 45^{\circ}C$	t = 10 ms (50) Hz, sine		7000	
	$V_R = 0 V$	t = 8.3 ms (60) Hz, sine		7600	
	$T_{VJ} = 150 ^{\circ}\text{C}$	t = 10 ms (50) Hz, sine		6100	
	$V_R = 0 V$	t = 8.3 ms (60) Hz, sine		6600	
ľt *	T _{vJ} = 45°C	t = 10 ms (50) Hz, sine		245000	Α
	$V_R = 0 V$	t = 8.3 ms (60) Hz, sine		239704	Α
	T _{VJ} = 150 °C	t = 10 ms (50) Hz, sine		186050	Α
	$V_R = 0 V$	t = 8.3 ms (60) Hz, sine		180774	Α
R _{thJC} *	DC current		0.155		
	ing to assembled produ			according to IE	K

^{*} Data according to assembled product

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